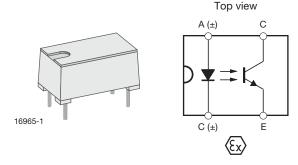


## Optocoupler, Phototransistor Output, ATEX Certified



#### **DESCRIPTION**

The CNY65Exi consists of a phototransistor optically coupled to an infrared-emitting diode in a 4 pin plastic package. The components are mounted opposite one another, with a distance between input and output of > 3.0 mm; meeting the highest of safety requirements.

The CNY65Exi is ATEX certificated for explosive atmospheres according to the European Guide line 94/9/EG.

### **AGENCY APPROVALS**

• ATEX (Ex):PTB 03 ATEX 2033 U EN 60079-0: 2012 + A11: 2013

EN 60079-11:2012 EN 60079-26: 2015

#### **FEATURES**

 ATEX certificate: PTB 03 ATEX 2033 U www.vishay.com/doc?85361



· Suitable for intrinsic safe circuits for gas and



Gas safety provision: II (1) G [Ex ia] IIC

• Dust safety provision: II (1) D [Ex ia] IIIC

Conforms to EN 60079-0: 2012 + A11: 2013

· Qualified for continuously, longterm, or frequently dangerous explosive environments, zone 0

Isolation voltage (V<sub>ISO</sub>) of 11 600 V<sub>peak</sub> for 1 minute

- Distance from emitter to detector through insulation ≥ 3 mm
- CTR from 50 % to 300 %
- Very low coupling capacity (C<sub>K</sub>)
  - 0.3 pF superior noise immunity between input and output pins
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- · Electronics used in potentially explosive gas and dust environments
  - Safety related process automation and instrumentation
  - Natural gas metering and flow measurement
  - Power and motor switching
  - Power supplies, metering, and data acquisition
  - Lighting and signaling
  - Petrol and grain transport and storage

ORDERING INFORMATION							
C N Y PART NUMBER	6 5 X  CTR BIN	PACKAGE C	OPTION DIP-4				
AGENCY CERTIFIED/PACKAGE	CTR (%)						
ATEX	50 to 300		100 to 200				
DIP-4, HV, high isolation distance	CNY65Exi CNY65BExi		CNY65BExi				



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		$V_{R}$	5	V				
Forward current		I <sub>F</sub>	75	mA				
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	Α				
Power dissipation		P <sub>diss</sub>	120	mW				
Junction temperature		Tj	100	°C				
OUTPUT	·							
Collector emitter voltage		$V_{CEO}$	32	V				
Emitter collector voltage		$V_{ECO}$	7	V				
Collector current		Ι <sub>C</sub>	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA				
Power dissipation		P <sub>diss</sub>	130	mW				
Junction temperature		Tj	100	°C				
COUPLER	· ·							
Total power dissipation		P <sub>tot</sub>	250	mW				
Ambient temperature range		T <sub>amb</sub>	-55 to +85	°C				
Storage temperature range		T <sub>stg</sub>	-55 to +100	°C				
Soldering temperature	2 mm from case, t ≤ 10 s	T <sub>sld</sub>	260	°C				

#### Note

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
Maximum Rating for extended periods of the time can adversely affect reliability

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I <sub>F</sub> = 50 mA	$V_{F}$	-	1.25	1.6	V		
OUTPUT								
Collector emitter voltage	I <sub>C</sub> = 1 mA	V <sub>CEO</sub>	32	-	-	V		
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7	-	-	V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_f = 0, E = 0$	I <sub>CEO</sub>	-	-	200	nA		
COUPLER								
Isolation resistance	$V_{IO} = 1 \text{ kV},$ 40 % relative humidity	R <sub>IO</sub> (1)	-	10 <sup>12</sup>	-	Ω		
Collector saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	V <sub>CEsat</sub>	-	-	0.3	V		
Cut-off frequency	$V_{CE} = 5 \text{ V, I}_{F} = 10 \text{ mA},$ $R_{L} = 100 \Omega$	f <sub>c</sub>	110	-	-	kHz		
Coupling capacitance	f = 1 MHz	C <sub>k</sub>	-	0.3	-	pF		

#### **Notes**

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements

(1) Related to standard climate 23/50 DIN 50014

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT							UNIT
1.7	V - 5 V I - 10 mA	CNY65Exi	CTR	50	100	300	%
I <sub>O</sub> /I <sub>F</sub>	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	CNY65BExi	CTR	100	-	200	%

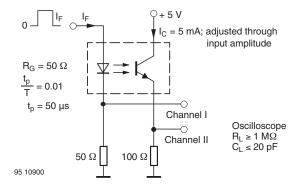


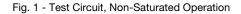
SAFETY AND INSULATION RATINGS						
PARAMETER		SYMBOL	VALUE	UNIT		
MAXIMUM SAFETY RATINGS						
Output safety power		P <sub>SO</sub>	250	mW		
Input safety current		I <sub>si</sub>	120	mW		
Safety temperature		T <sub>S</sub>	150	°C		
Comparative tracking index			475			
INSULATION RATED PARAMETERS						
Maximum withstanding isolation voltage			8200	V <sub>RMS</sub>		
Maximum transient isolation voltage			12 000	V <sub>peak</sub>		
Maximum repetitive peak isolation voltage			1450	V <sub>peak</sub>		
Insulation resistance	$T_{amb} = 25  ^{\circ}C,  V_{DC} = 500  V$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
Isolation resistance $T_{amb} = 100  ^{\circ}\text{C},  V_{DC} = 500  \text{V}$		R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
Climatic classification (according to IEC 68 part 1)			40 / 110 / 21			
Environment (pollution degree in accordance to DIN VDE 0109)			2			
Creepage			≥ 14	mm		
Insulation thickness	DTI	3	mm			

#### Note

According to DIN EN 60747-5-5 (see Fig. 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance
with the safety ratings shall be ensured by means of suitable protective circuits

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>d</sub>	-	2.6	-	μs
Rise time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>r</sub>	-	2.4	-	μs
Fall time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>f</sub>	-	2.4	=	μs
Storage time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>s</sub>	-	0.3	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>on</sub>	-	5	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 1)}$	t <sub>off</sub>	-	3	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega, \text{ (see Fig. 2)}$	t <sub>on</sub>	-	25	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega, \text{ (see Fig. 2)}$	t <sub>off</sub>	-	42.5	-	μs





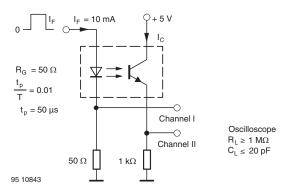


Fig. 2 - Test Circuit, Saturated Operation

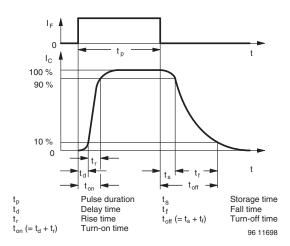


Fig. 3 - Switching Times

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

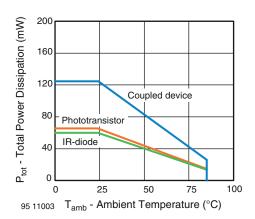


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

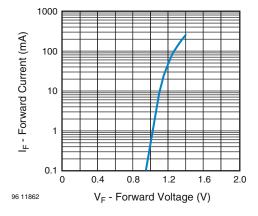


Fig. 5 - Forward Current vs. Forward Voltage

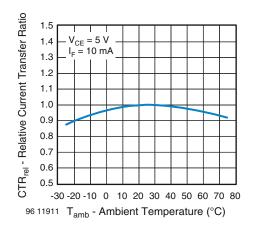


Fig. 6 - Relative Current Transfer Ratio vs.
Ambient Temperature

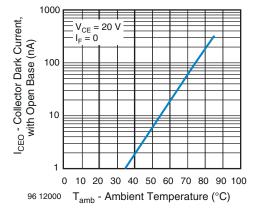


Fig. 7 - Collector Dark Current vs. Ambient Temperature



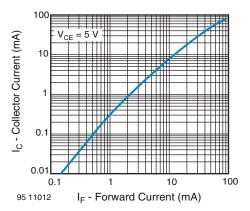


Fig. 8 - Collector Current vs. Forward Current

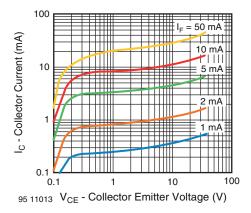


Fig. 9 - Collector Current vs. Collector Emitter Voltage

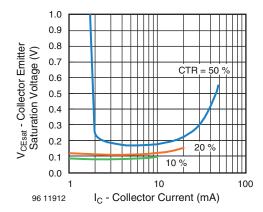


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

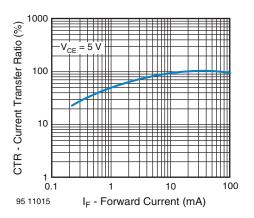


Fig. 11 - Current Transfer Ratio vs. Forward Current

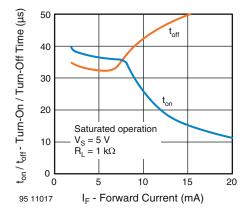


Fig. 12 - Turn-On / Turn-Off Time vs. Forward Current

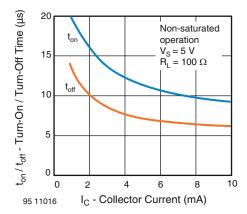
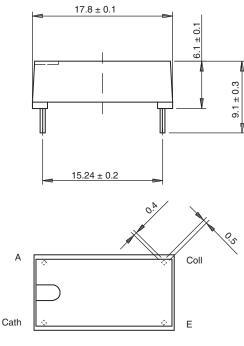


Fig. 13 - Turn-On / Turn-Off Time vs. Collector Current

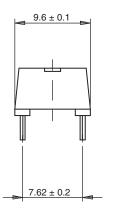
### **PACKAGE DIMENSIONS** (in millimeters)



Drawing-No.: 6.544-5036.01-1

Issue: 2; 10.11.98

14763



technical drawings according to DIN specifications

Weight: ca. 1.40 g Creepage distance: > 14 mm Air path: > 14 mm after mounting on PC board

### PACKAGE MARKING (example of CNY65BExi)



Fig. 14 - Top Marking

Theresienstrasse 2 74074 Heilbronn, Germany

Fig. 15 - Side Marking

TUBE INFORMATION						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
CNY65Exi	30	35	1050			



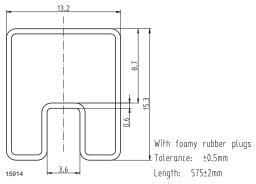


Fig. 16 - CNY65Exi

### **SOLDER PROFILES**

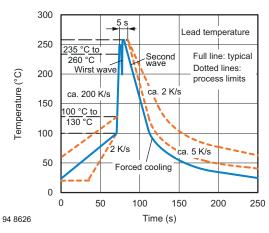


Fig. 17 - Wave Soldering Double Wave Profile According to J-STD-020 for Through-Hole Devices

### **HANDLING AND STORAGE CONDITIONS**

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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